

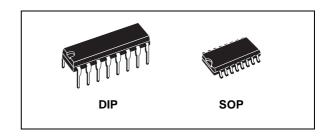
HCF4014B

SYNCHRONOUS PARALLEL OR SERIAL IN/SERIAL OUT 8 - STAGE STATIC SHIFT REGISTER

- MEDIUM SPEED OPERATION : 12 MHz (Typ.) At V_{DD} = 10V
- FULLY STATIC OPERATION
- 8 MASTER-SLAVE FLIP-FLOPS PLUS OUTPUT BUFFERING AND CONTROL GATING
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



The HCF4014B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. This device is an 8-stage parallel or serial input/serial output register having common CLOCK and PARALLEL/SERIAL CONTROL inputs, a single SERIAL data input, and individual parallel "JAM" inputs to each register stage. Each register stage is a D-type, master-slave flip-flop in addition to an output from stage 8, "Q" outputs are also available

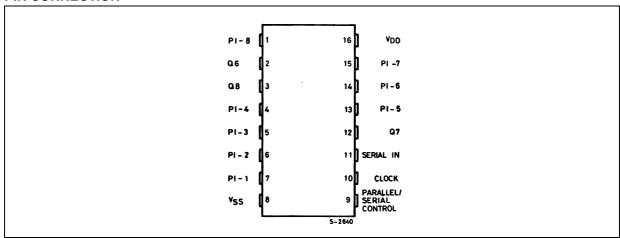


ORDER CODES

PACKAGE	TUBE	T&R
DIP	HCF4014BEY	
SOP	HCF4014BM1	HCF4014M013TR

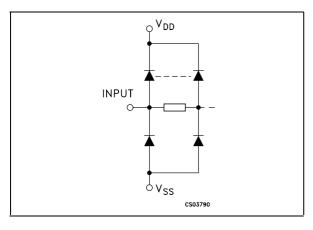
from stages 6 and 7. Parallel as well as serial entry is made into the register synchronously with the positive clock line transition. In this device, entry is controlled by the PARALLEL/SERIAL CONTROL input. When the PARALLEL/SERIAL CONTROL input is low, data is serially shifted into the 8-stage register synchronously with the positive transition of he clock line. When the PARALLEL/SERIAL CONTROL input is high, data is jammed into the 8-stage register via the parallel input lines and synchronous with the positive transition of the clock line.

PIN CONNECTION



October 2002 1/10

IINPUT EQUIVALENT CIRCUIT



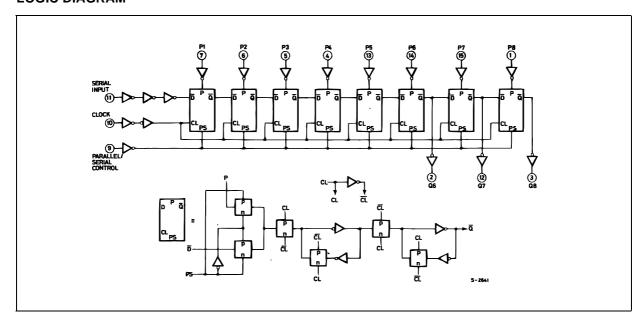
PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
7, 6, 5, 4, 13, 14, 15, 1	PI1 to PI8	Parallel Input
11	SERIAL IN	Serial Input
9	PARALLEL/ SERIAL CONTROL	Parallel/Serial Input Control
10	CLOCK	Clock Input
2, 3, 12	Q6, Q7, Q8	Buffered Outputs
8	V_{SS}	Negative Supply Voltage
16	V_{DD}	Positive Supply Voltage

TRUTH TABLE

CLOCK	SERIAL INPUT	PARALLEL/ SERIAL CONTROL	PI - 1	PI - n	Q ₁ (INTERNAL)	Q _n
	X	1	0	0	0	0
	Х	1	1	0	1	0
」	Х	1	0	1	0	1
」	X	1	1	1	1	1
	0	0	Х	Х	0	Q _n - 1
	1	0	Х	Х	1	Q _n - 1
	Х	Х	Х	Х	Q ₁	Q _n

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{DD}	Supply Voltage		3 to 20	V
VI	Input Voltage		0 to V _{DD}	V
T _{op}	Operating Temperature		-55 to 125	°C
t _r , t _f	Input Rise and Fall Time (PI-1 PI-8)	$V_{DD} = 5V$	0 to 1000	μs

DC SPECIFICATIONS

			Test Con	dition					Value				
Symbol	Parameter	Vı	v _o	l _o	V _{DD}	Т	$T_A = 25^{\circ}C$		-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(μA)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.04	5		150		150	
		0/10			10		0.04	10		300		300	μΑ
		0/15			15		0.04	20		600		600	μΑ
		0/20			20		0.08	100		3000		3000	
V _{OH}	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
V _{OL}	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
V _{IH}	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		
	Voltage		1/9	<1	10	7			7		7		V
			1.5/13.5	<1	15	11			11		11		
V_{IL}	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I _{OH}	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.1		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		IIIA
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
I _{OL}	Output Sink	0/5	0.4	<1	5	0.44	1		0.36		0.36		
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
l _l	Input Leakage Current	0/18	Any In	put	18		±10 ⁻⁵	±0.1		±1		±1	μΑ
C _I	Input Capacitance		Any In	put			5	7.5					pF

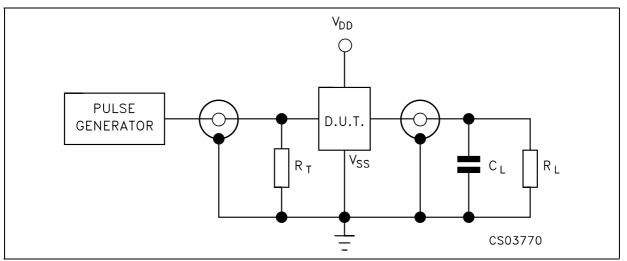
The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, $C_L = 50 pF$, $R_L = 200 K\Omega$, $t_r = t_f = 20 ns$)

0	D		Test Condition	,	Value (*)		
Symbol	Parameter	V _{DD} (V)		Min.	Тур.	Max.	
		CLO	CKED OPERATION	I		<u> </u>	<u> </u>
t _{PLH} t _{PHL}	Propagation Delay Time	5			160	320	
		10			80	160	ns
		15			60	120	
t _{THL} t _{TLH}	Transition Time	5			100	200	
		10			50	100	ns
		15			40	80	
f _{CL} ⁽¹⁾	Maximum Clock Input	5		3	6		
OL	Frequency	10		6	12		MHz
	t Clock Bulgo Width	15		8.5	17		
t _W	Clock Pulse Width	5		180	90		
		10		80	40		ns
		15		50	25		
t _r , t _f	Clock Input Rise or Fall	5				15	
	Time	10				15	μs
		15				15	
t _{setup}	Setup Time, serial Input	5		120	60		
•	(ref to CL)	10		80	40		ns
		15		60	30		
t _{setup}	Setup Time, Parallel Inputs	5		80	40		
	(ref to CL)	10		50	25		ns
		15		40	20		
t _{setup}	Setup Time, Parallel/Serial	5		180	90		
	Control (ref to CL)	10		80	40		ns
		15		60	30		1
t _{hold}	Hold Time, serial in,	5		0			
	parallel in, parallel /serial	10		0			ns
	control	15		0			1

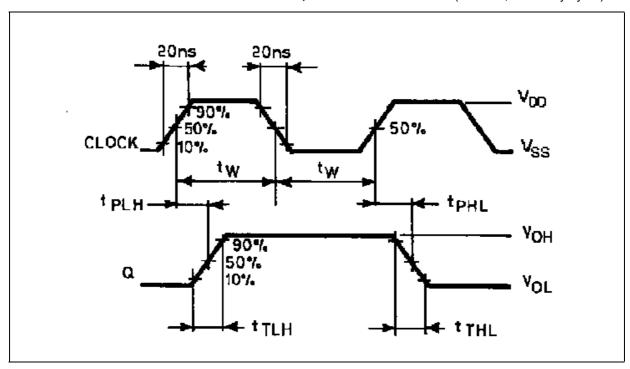
^(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.
(1) If more than one unit is cascaded t_rCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage of the estimated capacitive load.

TEST CIRCUIT

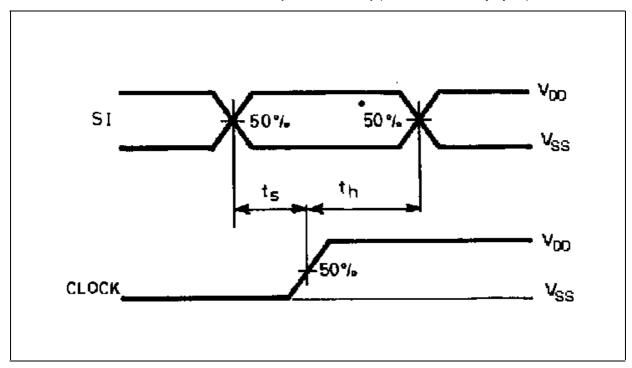


 C_L = 50pF or equivalent (includes jig and probe capacitance) R_L = 200KΩ R_T = Z_{OUT} of pulse generator (typically 50Ω)

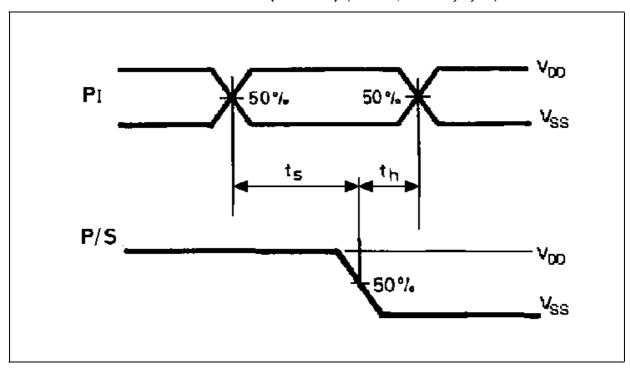
WAVEFORM 1: PROPAGATION DELAY TIMES, CLOCK PULSE WIDTH (f=1MHz; 50% duty cycle)



WAVEFORM 2: SETUP AND HOLD TIMES (SI TO CLOCK) (f=1MHz; 50% duty cycle)

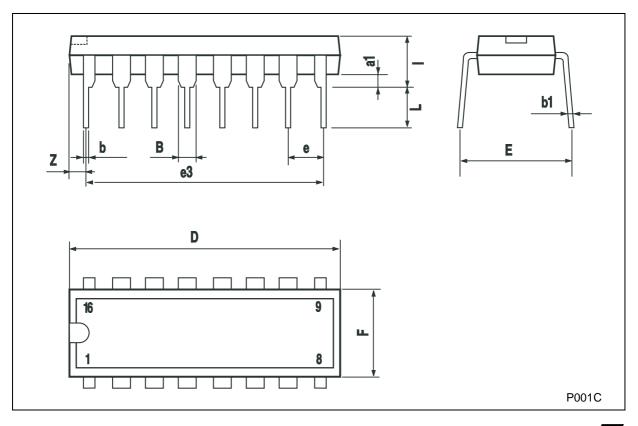


WAVEFORM 3: SETUP AND HOLD TIME (PI TO P/S) (f=1MHz; 50% duty cycle)



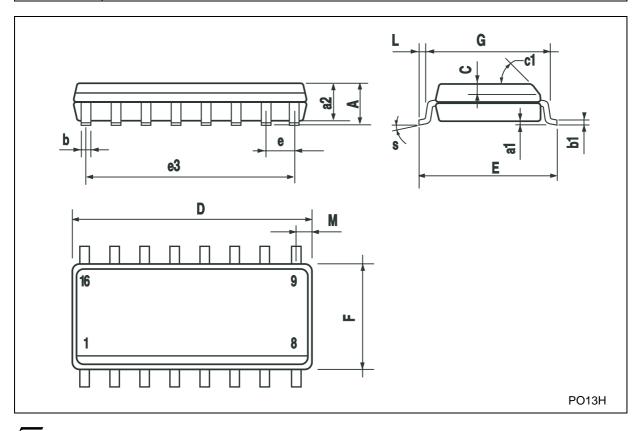
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
Е		8.5			0.335	
е		2.54			0.100	
еЗ		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



SO-16 MECHANICAL DATA

DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)		
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024
S		1	ຊໍ (ເ	max.)	1	1



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